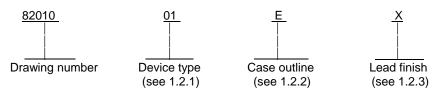
LTR						DESCF	RIPTIO	N					DA	ATE (YI	R-MO-I	DA)		APPF	ROVED	
A	Adde revis		idor C	AGE 0)1295	with de	evice t	ypes C)4 - 07	comp	lete			83-1	0-07		N. A	. Hau	ck	
В	Adde from	ed dev an ap	vice typ prove	pes 08	8, 09, 1 rce. In	to dev I0. De nactiva	vice ty	/pes 0	4 and	05 not	availa	ble		86-0)1-20		N. A	. Haud	ck	
С	Char	nge lin	nits of	toff a	nd trm	w. Edi	itorial o	change	es thro	ughou	t.			86-0)5-23		R. F	. Evar	าร	
D				AGE 6 format		with d	evice t	ypes ()4 and	05. C	hange	ed to		87-0)4-28		N. A	. Haud	ck	
E	Char	nges ii	n acco	ordanc	e with	NOR	5962-F	R157-9	96.					96-0)6-26		M. A	A. Frye)	
F						provisi CAGE					certifie	ed		00-1	2-22		Ray	mond	Monni	n
G	Corr ksr	ection	to ma	irking p	baragr	aph 3.	5, upd	lated b	oilerpl	ate pa	ragrap	ohs.		05-0)3-02		Ray	mond	Monni	n
Н	Boile	erplate	upda	te, par	t of 5	year re	eview.	ksr						10-1	1-17		Cha	rles F.	Saffle	•
THE ORIGIN		-			S DRA	AWING	6 HAS	BEEN	I REPL	ACED).									
CURRENT C REV SHEET REV		-			S DRA		B HAS	BEEN).									
CURRENT C REV SHEET REV SHEET	H 15	ODE I H	S 672	68. H 18								н	Ξ	н	н	н	н	н	н	н
CURRENT C REV SHEET REV	AGE C H 15 JS	ODE I H	S 672	68. H 18 RE [\]			HAS	BEEN H	REPL	ACED). H5	H	H 7	H 8	H 9	H 10	H 11	H 12	H 13	H 14
CURRENT O REV SHEET REV SHEET REV STATU	AGE C H 15 JS	ODE I H	S 672	68. H 18 RE [\] SHE	V EET	ED BY	H	H	H	H	H	6	7	8	9		11	12		
CURRENT O REV SHEET REV STATU OF SHEETS PMIC N/A	AGE C H 15 JS S	ODE I H 16	S 672	68. H 18 RE\ SHE PRE	V EET Darrell	ED BY	H 1	H	H	H	H	6 D	7 LA L LUME	8 AND BUS,	9 ANE OHI	10	11 RITIN 218-3	12		
CURRENT O REV SHEET REV SHEET REV STATL OF SHEETS PMIC N/A	AGE C H H 15 JS S NDAF OCIRC AWIN AILABLI	ODE I H 16 SUIT G	S 672	68. H 18 REV SHE CHE CHE	V EET EPARE Darrell C. R. J	ED BY I Hill D BY	H 1	H	H	н 4	H 5	6 D COI		8 AND BUS, p://wv	9 ANE OHIO WW.ds	10 0 MA 0 43 cc.dla	11 RITIN 218-: mil	12 NE 3990 DIGI	13 TAL	,
CURRENT C REV SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA MICRO DR THIS D AV/ FOR U AND AGE	AGE C H 15 JS S NDAF OCIRC AWIN AILABLI USE BY RTMEN NCIES (ODE I H 16 20 20 20 20 30 5 31 5 4 11 31 5 5 7 4 11 31 5 5 7 4 11 31 5 5 7 4 11 31 5 5 5 7 4 11 31 5 5 5 7 5 7 5 7 5 7 5 7 5 7 5 7 5 7 5	S 672 Н 17	68. H 18 REV SHE CHE C C APP V	V EET EPARE Darrell ECKEE C. R. J PROVE	ED BY I Hill D BY acksor ED BY ED BY E. Sh G APPI	H 1 oup	H 2	H 3	H 4 MIQ NM	H 5 CRC	6 D COI	7 LA L LUME http RCU ,536	8 BUS, p://wv	9 ANE OHIO W.ds	10 0 43 cc.dla	11 RITIN 218-: mil	12 NE 3990 DIGI	13 TAL	,
CURRENT C REV SHEET REV SHEET REV STATU OF SHEETS PMIC N/A PMIC N/A STA MICRO DR THIS D AV/ FOR U DEPARTME	AGE C H 15 JS S NDAF OCIRC AWIN AILABLI USE BY RTMEN NCIES (ODE I H 16 RD UIT G IG IS E AII ITS OF TH DEFE	S 672 Н 17	68. H 18 RE ^V SHI CHE C C APP V DRA	V EET Darrell ECKEI C. R. J PROVE Villiam	ED BY I Hill D BY acksor ED BY E. Sh S APPI 82-C	H 1 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	H 2	H 3	H 4 MIQ NM		6 COI COIF , 65 DLITH	7 LA L LUME http RCU ,536	8 BUS, p://wv IT, I SIL	9 ANE OHIO W.ds	10 0 43 cc.dla	11 RITIN 218-3 mil	12 NE 3990 DIGI	13 TAL RAN	,

1. SCOPE

1.1 <u>Scope</u>. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.

1.2 <u>Part or Identifying Number (PIN)</u>. The complete PIN shall be as shown in the following example:



1.2.1 <u>Device types</u>. The device types shall identify the circuit functions as follows:

Device type	<u>Generic number</u> <u>1</u> /	<u>Circuit</u>	Access time	<u>Refresh</u>
01	65	5,536 X 1-bit RAM	150 ns	128 cycles (1 ms)
02	65	5,536 X 1-bit RAM	150 ns	128 cycles (2 ms)
03	65	5,536 X 1-bit RAM	200 ns	128 cycles (2 ms)
04	65	5,536 X 1-bit RAM	150 ns	256 cycles (4 ms)
05	65	5,536 X 1-bit RAM	200 ns	256 cycles (4 ms)
06	65	5,536 X 1-bit RAM	150 ns	256 cycles (4 ms)
07	65	5,536 X 1-bit RAM	200 ns	256 cycles (4 ms)
08	65	5,536 X 1-bit RAM	120 ns	256 cycles (4 ms)
09	65	5,536 X 1-bit RAM	150 ns	128 cycles (2 ms)
10	65	5,536 X 1-bit RAM	200 ns	128 cycles (2 ms)

1.2.2 <u>Case outlines</u>. The case outlines shall be as designated in MIL-STD-1835, and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
E	GDIP1-T16 or CDIP2-T16	16	dual-in-line package
Z	CQCC3-N18	18	rectangular chip carrier package

1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.

1.3 Absolute maximum ratings.

Supply voltage range	-1.5 to +7.0 V dc
Storage temperature range	-65°C to +150℃
Maximum power dissipation (P _D)	
(minimum cycle time)	1.0 W
Lead temperature (soldering, 5 seconds)	
Thermal resistance, junction-to-case (θ_{JC}):	See MIL-STD-1835
Junction temperature (T _J)	+150℃
Short circuit output current	150 mA

1/ Generic numbers are listed on the Standard Microcircuit Drawing Source Approval Bulletin at the end of this document and will also be listed in MIL-HDBK-103 and QML-38535, as applicable (see 6.6 herein).

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1.4 Recommended operating conditions.

Supply voltage Maximum low-level input voltage (V _{IL}):	4.5 V dc to 5.5 V dc
Device types 01, 02, and 03	-1.5 V dc to 0.8 V dc
Device types 04, 05, 06, 07, and 08	-0.6 V dc to 0.8 V dc
Device types 09 and 10	-1.0 V dc to 0.8 V dc
Maximum high-level input voltage (V _{IH}):	
Device types 01, 02, and 03	2.4 V dc to 6.5 V dc
Device types 04, 05, 06, 07, and 08	2.4 V dc to 5.8 V dc
Device types 09 and 10	
Refresh cycle time:	
Device type 01	1.0 ms
Device types 02, 03, 09, and 10	
Device types 04, 05, 06, 07, and 08	4.0 ms
Case operating temperature range:	
Device types 01, 02, 03, 06, 07, 08, 09,	
and 10	-55°C to +110℃
Device types 04 and 05	-55℃ to +125℃

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883	-	Test Method Standard Microcircuits.
MIL-STD-1835	-	Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings. MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <u>https://assist.daps.dla.mil/quicksearch/</u> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 <u>Item requirements</u> The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturer's approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used. This drawing has been modified to allow the manufacturer to use the alternate die/fabrication requirements of paragraph A.3.2.2 of MIL-PRF-38535 or alternative approved by the Qualifying Activity.

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3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.

3.2.1 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.

3.2.2 Truth table. The truth table shall be as specified on figure 2.

3.2.3 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.

3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.

3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked.

3.5.1 <u>Certification/compliance mark</u>. A compliance indicator "C" shall be marked on all non-JAN devices built in compliance to MIL-PRF-38535, appendix A. The compliance indicator "C" shall be replaced with a "Q" or "QML" certification mark in accordance with MIL-PRF-38535 to identify when the QML flow option is used. For product built in accordance with A.3.2.2 of MIL-PRF-38535 the "D" certification mark shall be used in place of the "C" certification mark.

3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.

3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 <u>Notification of change</u>. Notification of change to DLA Land and Maritime-VA shall be required for any change that affects this drawing.

3.9 <u>Verification and review</u>. DLA Land and Maritime, DLA Land and Maritime's agent and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

4. VERIFICATION

4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

- a. Burn-in test (method 1015 of MIL-STD-883).
 - (1) Test condition D or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or procuring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

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	1	TABLE I. Electrical perform Conditions	Group A	Device	Limit	<u> </u>	
Test	Symbol	$-55^{\circ}C \le T_{C} \le +110^{\circ}C, \ 1/$ unless otherwise specified	Group A subgroups	1	<u>Limit</u> Min 	Max 	Unit
High-level output voltage	V _{он}	$ V_{DD} = 5 \text{ V}, V_{IN} = 0 \text{ or } V_{DD}$ $ I_{OH} = -5 \text{ mA}$	1, 2, 3	All	2.4		V
Low-level output voltage	V _{OL}	$ V_{DD} = 5 V, V_{IN} = 0 \text{ or } V_{DD}$ $ I_{OL} = 4.2 \text{ mA}$	1, 2, 3	All		0.4	
Supply current, standby	I _{DD1}	$ V_{DD} = 5 V, CAS = RAS = V_{IH}$ $D_{OUT} = High Z$	1, 2, 3	All		5	mA
Supply current, operating	I _{DD2} <u>2</u> /	$ V_{DD} = 5 V$, RAS and CAS cycling $t_{CYC} = t_{RC}$ min	1, 2, 3 	01,02,03, 04,05,06, <u>07,08,09</u>		60 	mA
			1	10		55	
Supply current,	I _{DD3}	$ V_{DD} = 5 V, RAS = cycling,$	1, 2, 3	01,02,03,		45	mA
RAS only cycle		$ t_{CYC} = t_{RC} min, CAS = V_{IH}$		04,05,06, <u>07,08,09</u>			
				10		•	
Supply current,	I _{DD4}	$ RAS = V_{IL}, CAS cycling$	1, 2, 3	09		-	mA
PAGE mode		t _{pc} = min		10		40	
High-level input leakage current	I _{IH}	V _{DD} = 5 V, V _{IN} = 5.0 V	1, 2, 3	All		10	μA
Low-level input leakage current	I _{IL}	$V_{DD} = 5 V, V_{IN} = 0.8 V$	1, 2, 3	All		-10	μA
High-level output leakage current	 I _{ОН} 	$ V_{DD} = 5 V, V_{OUT} = 5.5 V$ $ \overline{RAS} = \overline{CAS} = V_{H}$	 1, 2, 3 	All		 10 	 μΑ
5							
Low-level output	I I _{OL}	V _{DD} = 5 V, V _{OUT} = GND	1, 2, 3	All		-10	 μΑ
leakage current		$ \overline{RAS} = \overline{CAS} = V_{IH}$				ļ	
				01,02,03,			1
nput capacitance (A ₀ - A ₇)	C ₁ <u>3</u> /	T _C = +25°C	4	<u>09,10</u> 04,05,		Max 0.4 5 5 60 55 45 45 40 40 45 40 10 10 10 10 10	 ∣pF
(,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,				06,07,08			
Input capacitance	 C ₂ <u>3</u> /	 T _C = +25°C	4	 01,02,03,		 10	 pF
(RAS, CAS, DIN,				04,05,06,			
WE)				07,08			1
			ļ	09,10		7	
See footnotes at enc	l of table.						
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	TABLE	E I. <u>Electrical performar</u>	nce characteri	istics -	Continue	ed			
Test	 Symbol	Conditions -55⁰C <u><</u> T _C <u><</u> +11 unless otherwise s			oup A ogroups	Device type	<u>Lim</u> Min	its Max 	⊥ ∣Unit
Output capacitance (RAS)	С _{оит} <u>3</u> /	T _C = +25°C		4		01,02,03, 04,05,06, 07,08		8	pF
						09,10		6	
Access time from RAS	 +				- 11		1	150	1
Access time from RAS	t _{RAC} <u>4</u> / <u>5</u> / 	See figure 3 		9, 1(<i>J</i> , II	<u>04,06,09</u> 03,05, <u>07,10</u>	 	200	_ ns │ ⊥
				İ		08		120	Ī
						04,06,10	<u> </u>	100	Ļ
Access time from	t _{CAC}	See figure 3		9, 10	D, 11	01,02		90	ns
CAS	<u>3/ 4/ 5</u> /					03		120	1
						<u>05,07</u>		135	\perp
				ļ		08	ļ	70	Ļ
						09	ļ	75	
Time between	t _{REF}	See figure 3		9, 10	J, 11	01	ļ	1.0	⊥ ms
refresh						<u>02,03,09,10</u> 04, 05,		<u>2.0</u> 4.0	+
						06,07,08		4.0	
				1		04	160		1
 RAS precharge	1	See figure 3		9, 10	11	01,02,06,09	100	I	⊥ ∣ns
time	t _{RP}			9, 10	J, П	03	135	I	1 115
une						05	200		+
				Ì		07,10	120	1	+
				i		08	80		Ť
CAS precharge time (nonpage cycles)	t _{CPN}			9, 1(D, 11	<u>09</u> 10	30		ns
CAS to RAS pre- charge time	∣t _{CRP}	See figure 3		9, 10 	D, 11	All	0		ns
						04	20	50	\perp
RAS to CAS delay	t _{RCD}	See figure 3		9, 10	D, 11	01,02,06	30	60	ns
time					,	03,07	35	80	Ì
	İ	İ		i		05	25	65	Ļ
						08	15	50	\downarrow
				ļ		09	30	75	Ļ
						10	35	100	
	I			I			100		+
RAS hold time	t _{RSH}	See figure 3		9, 10	D, 11	01,02	90	<u> </u>	⊥ ns
						03	120		+
						<u>05,07</u> 08	<u> 135</u> 60		÷
						09	75		+
						04,06			
CAS hold time	+	Soo figuro 2			1 1 I		150	i I	1 00
	∣t _{CSH}	See figure 3		9, 10 	D, 11	<u>01,02,09</u> <u>03,05,07,10</u>	<u>150</u> 200	 	⊥ns ⊢
						03,05,07,10	1200		4
See footnotes at end of tabl	e.								1
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		Conditions	Group A	Device	Limits	3	L
Test	Symbol	-55°C \leq T _C \leq +110°C, <u>1</u> / unless otherwise specified	subgroups	type	Min	Max	Unit
Row address setup time	 t _{ASR} 	 See figure 3 	 9, 10, 11	01,02,03, 06,07,08, 09,10	0		 ns
				04,05	5		
				01,02,			
Row address hold	t _{RAH}	See figure 3	9, 10, 11	04,06,09	20	<u> </u>	⊥ ns
time		1	1	<u>03,07,10,</u> 08	<u> 25</u> 15	- <u> </u>	∔
	+	+		01,02,03,	<u> </u>	<u> </u>	
	İ		İ	04,05,09,	0	İ	İ
Column address	t _{ASC}	See figure 3	9, 10, 11	10			ns
setup time	<u> </u>	<u> </u>		06,07,08	-5	<u> </u>	<u> </u>
Column address	 +	 See figure ?		04	60		L L na
Column address hold time	∣t _{CAH}	See figure 3	9, 10, 11 	<u>01,02,09</u> <u>03,08,10</u>	<u>30</u> 40		⊥ ns
		1	1	03,08,10 05	40		⊥
				06	45	<u> </u>	⊥
				07	55	<u> </u>	+
	1	· 		04,06	95		
Column address	t _{AR}	See figure 3	9, 10, 11	01,02	100		⊥ ∣ns
		1	, ., . . ,		•		+ ···
hold time, to RAS		1		03	130		Ļ
	1	1		<u>05,07,10</u> 08	<u> 140</u> 85		Ļ
		1	1	08	85		⊥
	- <u>+</u>	+		01,02,03,	100		<u> </u>
Transition time	 t _T	 See figure 3 <u>6</u> /	 9, 10, 11	01,02,03,	 3	50	 ns
	1		0, 10, 11 	00,07,08,	, J	33	13
	1			04,05	3	20	+
		ĺ		03,04,07,	0	50	<u> </u>
	İ		i	10	ĺ		Ĺ
Output buffer	t _{OFF}	See figure 3 <u>7</u> /	9, 10, 11	01,02	0	40	⊥ ⊥ns
turn-off delay		i .		06,08,09	0	40	L
		l		05	0	60	<u> </u>
Read and refresh		See figure 3		04	330	1,500	Ļ
cycles:		!	9, 10, 11	01,02,06	260	10,000	⊥ns
Random read cycle	t _{RC}		ļ	03	345	10,000	Ļ
time		1		05	420	1,500	Ļ
		1		07	330	10,000	Ļ
	1	1	1	08	230	-	Ļ
		1	1	<u>09</u> 10	260		+
	+	<u> </u>	<u> </u>	04	150	1,500	<u> </u>
	1		1		•	•	+
RAS pulse width	t _{RAS}	See figure 3	9, 10, 11	01,02,06,09		10,000	⊥ns
			ļ	03,07,10	200	10,000	Ļ
		1		05	200	1,500	Ļ
		1		08	120	10,000	<u> </u>
See footnotes at end	of table.		22	<u>2-</u> ,			
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	1	TABLE I. <u>Electrical performance</u> Conditions	Group A	Device	Limit		1
Test	 Symbol 	Conditions $-55^{\circ}C \le T_{c} \le +110^{\circ}C, \ \underline{1}/$ unless otherwise specified	Group A subgroups 		<u>Limit</u> Min 	s Max 	⊥ Unit
	<u> </u>			_04	100	1,500	↓
CAS pulse width	t _{CAS}	See figure 3	9, 10, 11	01,02	90	10,000	ns
·				03	120	10,000	Ī
				05	135	1,500	Ļ
				06,10	100	10,000	Ļ
				<u>07</u> 09	<u>135</u> 75	10,000	Ļ
Read command set- up time	t _{RCS}	See figure 3	9, 10, 11	All	0	 	ns
Read command hold time	t _{RCH}	See figure 3	9, 10, 11	All	0		ns
			İ	_04	330	1,500	Ĺ
Write cycle:		See figure 3		07	330	10,000	1
Random write	t _{wc}		9, 10, 11	<u>01,02,06</u> 03	260 345	10,000	⊥ ns
cycle time	1	1		03	<u>345</u> 420	<u>10,000</u> 1,500	⊥
	1	1		08	230	1,000	+
				09	260		÷ L
		ļ		10	330		
Write command setup time	∣t _{wcs} ∣	See figure 3	9, 10, 11 	01,02,03, 04,05,06,07	0		∣ ns ⊥
			ļ	08	-5		Ļ
	1	1		09,10	-10		
Write command	∣ ∣t _{wcн}	 See figure 3	9, 10, 11	<u>04,06</u> 01,02,10	60 45		⊥ ∣ns
hold time	WCH		3, 10, 11	03	55		_ 113
			Ì	05,07	80		÷ Ĺ
	İ	İ	İ	08	40		Ī
				09	35		ļ
Write command		 See figure 3	 9, 10, 11	<u>04</u> <u>01,02</u>	<u>125</u> 120		1
hold time to	∣t _{WCR} ∣		9, 10, 11 	<u>01,02</u> <u>03</u>	120		⊥ ns ⊥
RAS				05	160		Ļ
			ļ	06,09	110		Ļ
				07,10	145		Ļ
				08	85		
Write command	t _{WP}	See figure 3	9, 10, 11	04,06,10	45		ns
pulse width			-,,	03,05,07	55		+•
				08	25		Ļ
				09	35		
Write command to	 t	 See figure 2		04,06	60		⊥ Lnc
	t _{RWL}	See figure 3	9, 10, 11	01,02,09	45		⊥ ns
RAS lead time				03,10	55		Ļ
				<u>05,07</u> 08	80 50		Ļ
See footnotes at end	of table.	1	ļ			1	
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		Conditions	Group A	Device	Limit	S	
Test	Symbol	$-55^{\circ}C \le T_{C} \le +110^{\circ}C, 1/$ unless otherwise specified	subgroups		Min	Max	Unit
				04,06	60		Ļ
Write command to	t _{CWL}	See figure 3	9, 10, 11	01,02,09	45		ns
CAS lead time			I	03,10	55		L
			ļ	05,07	80		Ļ
				08	50		
Data-in setup time	t _{DS}	See figure 3	9, 10, 11	All	0		ns
				04,06	60		Ļ
Data-in hold time	t _{DH}	See figure 3	9, 10, 11	01,02,10	45		⊥ns
				<u>03</u> 05,07	55 80		Ļ
	1			05,07	80		L I
	1	1		09	35		<u>⊢</u>
	+	<u> </u>		03	125		
Data-in hold time,	t _{DHR}	See figure 3	9, 10, 11	01,02	120		⊥ L_ns
toRAS	1	· -		03	150		
	1	1		03	160		⊥
		1		06,09	110		⊥
	1	1		07,10	145		+
				08	85		÷ L
				01,02	280	10,000	Ĺ
Read modify write	t _{RMW}	See figure 3	9, 10, 11	04	345	1,500	L
cycle time				05	425	1,500	Ļ
				06	285	10,000	Ļ
				08	260	10,000	⊥ ns
				03	370 345	10,000	Ļ
	1	1		07	280	10,000	⊥
	1	1		10	345		⊾
	+	<u> </u>		04,06	110		L
RAS to WE delay	+	See figure 2		01,02,09	120	·	
TAS IU WE DELAY	t _{RWD}	See figure 3	9, 10, 11	01,02,09	120		⊥ns
		1		05,07	130		1
	1			08	85		+
				<u>10</u>	155		
	Ì			04,06	60		Ĺ
CAS to WE delay	t _{CWD}	See figure 3	9, 10, 11	01,02,10	55		- ns
CITO TO VVE UCIAY	I "CWD	 	0, 10, 11	03	80		L'''3
	1			05,07	65		+
			İ	08	40		Ī
				09	45		
Read command				01,02,04,05			Ļ _
nold time	t _{RRH}	See figure 3	9, 10, 11	03	25		⊥ ns
referenced to RAS				06,07,08	5		Ļ
.		I		09,10	0		I
See footnotes at end	of table.						
	STAND	ARD	SIZE				
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TABLE I. <u>Electrical performance characteristics</u> - Continued.

Conditions		Conditions	Group A	Device	Limits		
Test	Symbol	$-55^{\circ}C \le T_{C} \le +110^{\circ}C, \ 1/$ unless otherwise specified	subgroups	type	Min	Max 	Unit
Page mode read or write cycle	 t _{PC} 	 See figure 3 	 9, 10, 11 	09 10	 <u>145</u> 190		 ns
CAS precharge time, page mode	 t _{CP} 	See figure 3	 9, 10, 11 	<u>09</u> 10	<u>60</u> 80	 	ns

<u>1</u>/ Device types 04 and 05, $T_C = -55^{\circ}C$ to +125°C.

- $\frac{2}{I_{DD}}$ is dependent on output loading and cycle rates. The I_{DD} measurements are made with the outputs open. Limits are for cycle rates listed in condition column and worst case data pattern (alternate "1" and "0") at a PRR = 4.0 MHz. T_{CYC} = T_{RC} min.
- $\underline{3}$ / Capacitance measured with Boonton meter or equivalent or effective capacitance calculated from the equation $C = \underline{I\Delta t} \text{ with } \Delta V \text{ equal to 3 volts and } V_{CC} = 5.0 \text{ V}.$ ΔV
- $\underline{4}$ Load = One Schottky TTL +100 pF or equivalent for device types 01, 02, and 03.
- 5/ Load = Two Schottky TTL +100 pF or equivalent for device types 04, 05, 06, 07, 08, 09, and 10.
- $\underline{6}$ / Devices are tested at t_T = 5 ns, where t_T is the rise and fall time for RAS and CAS .
- 7/ Tested only initially and after any design changes.

MIL-STD-883 test requirements	Subgroups (in accordance with MIL-STD-883, method 5005,table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 3, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 9

TABLE II. Electrical test requirements.

* PDA applies to subgroup 1.

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Device types	А	JI
Case outlines	Е	Z
Terminal number	Termina	l symbol
1	NC	NC
2	D _{IN}	D _{IN}
3	WE	WE
4	RAS	RAS
5	A ₀	NC
6	A ₂	A ₀
7	A ₁	A ₂
8	V_{DD}	A ₁
9	A ₇	V _{DD}
10	A ₅	A ₇
11	A ₄	A ₅
12	A ₃	A ₄
13	A ₆	A ₃
14	D _{OUT}	NC
15	CAS	A ₆
16	V_{SS}	D _{OUT}
17		CAS
18		V _{SS}

FIGURE 1. Terminal connections.

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Truth Table							
	INPUTS						
Operation <u>7</u> /	RAS	CAS	D _{IN}	Address	Write	D _{OUT} <u>1</u> /	
Chip not selected	Н	Н	X <u>2</u> /	х	Х	High Z	
Write "L" in cell A _{xy} <u>3</u> /	L	L	L	A _{xy}	L	High Z <u>4</u> /	
Write "H" in cell A _{xy}	L	L	Н	A _{xy}	L	High Z <u>4</u> /	
Read data in cell A_{xy}	L	L	Х	A _{xy}	Н	Data (A _{xy})	
RAS only refresh	L	н	х	A _x <u>5</u> /	х	High Z	
Hidden RAS only refresh	L	L	Н	A _x	Н	Data (A _{x-N,y-N}) <u>6</u> /	

NOTES:

 $\underline{1}$ / D_{OUT} is not inverted from D_{IN} .

<u>2</u>/ "X" = Don't care.

 $\underline{3}$ / A_{xy} denotes proper address logic to address cell A_{xy} .

4/ For "EARLY WRITE" timing, data out remains at high impedance. For "LATE WRITE" timing, data out is valid from access time to the beginning of a subsequent cycle, or until CAS goes to a high level.

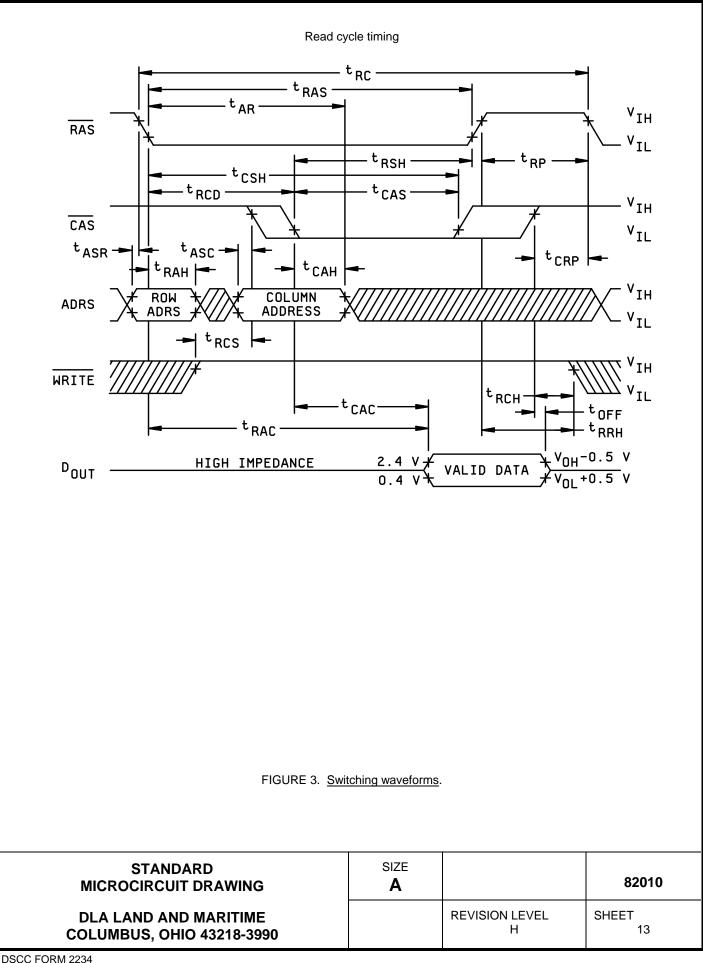
 $\underline{5}$ / A_x depends only on A₀-A₆; A₇ is a don't care.

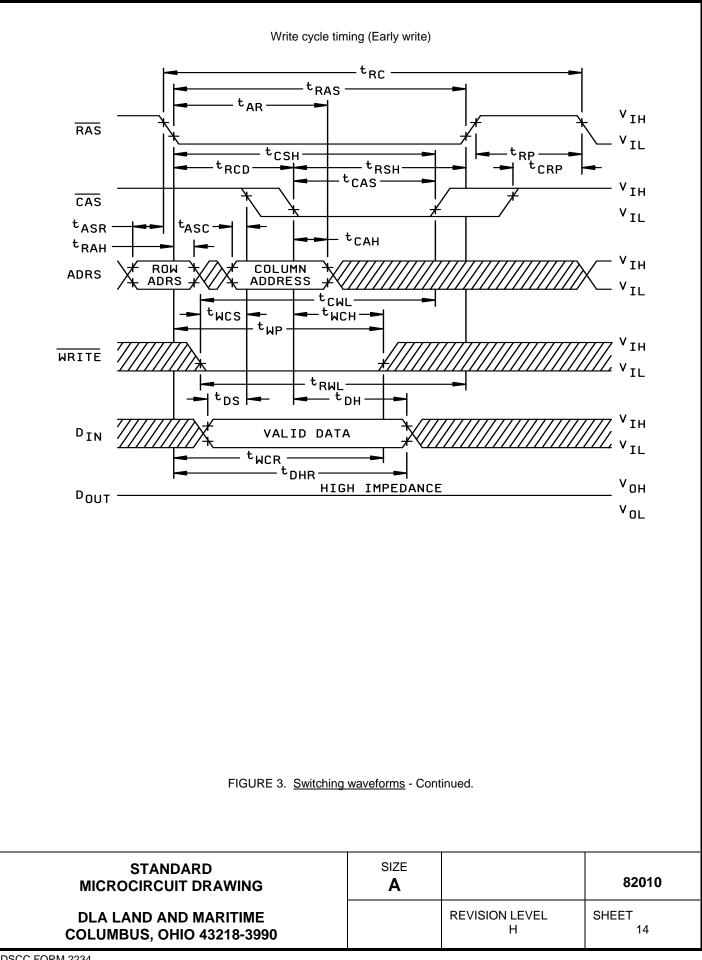
 $\underline{6}$ When CAS = V_{IL}, the data output will contain data from the last valid read cycle (i.e., N cycles before).

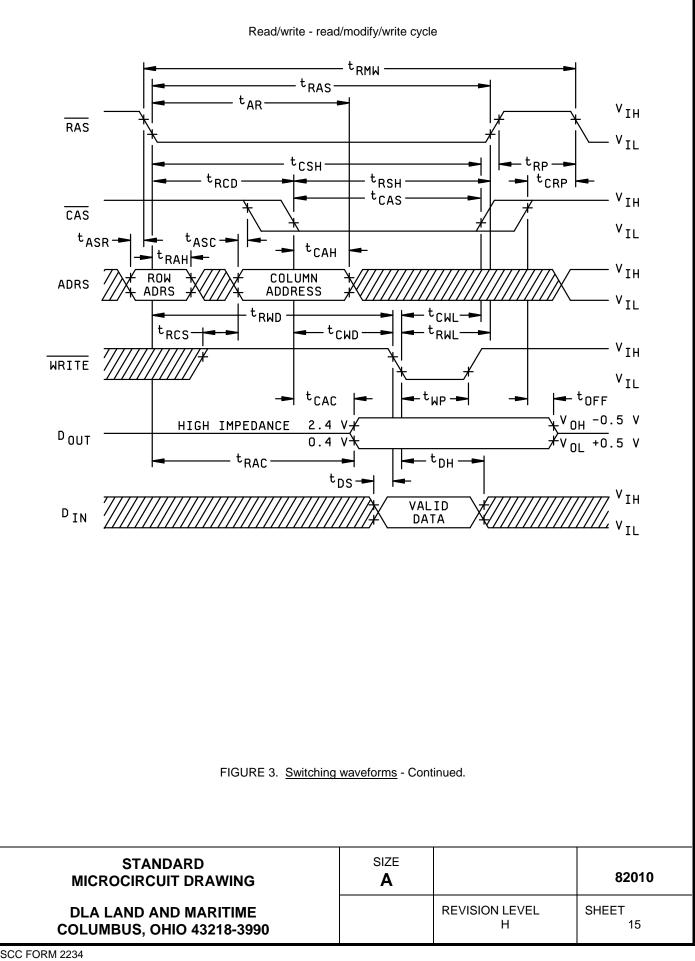
<u>7</u>/ A 500 μs pause and eight initialization cycles required before truth table applies. All timing requirements shall be applied.

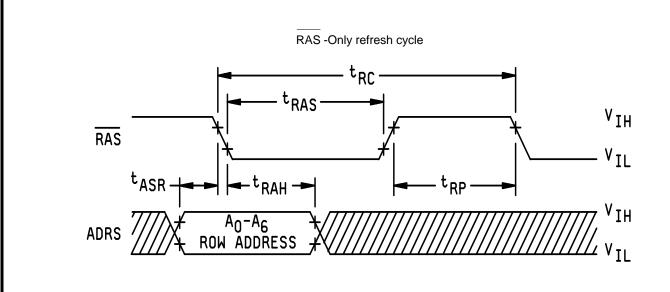
FIGURE 2. Truth table.

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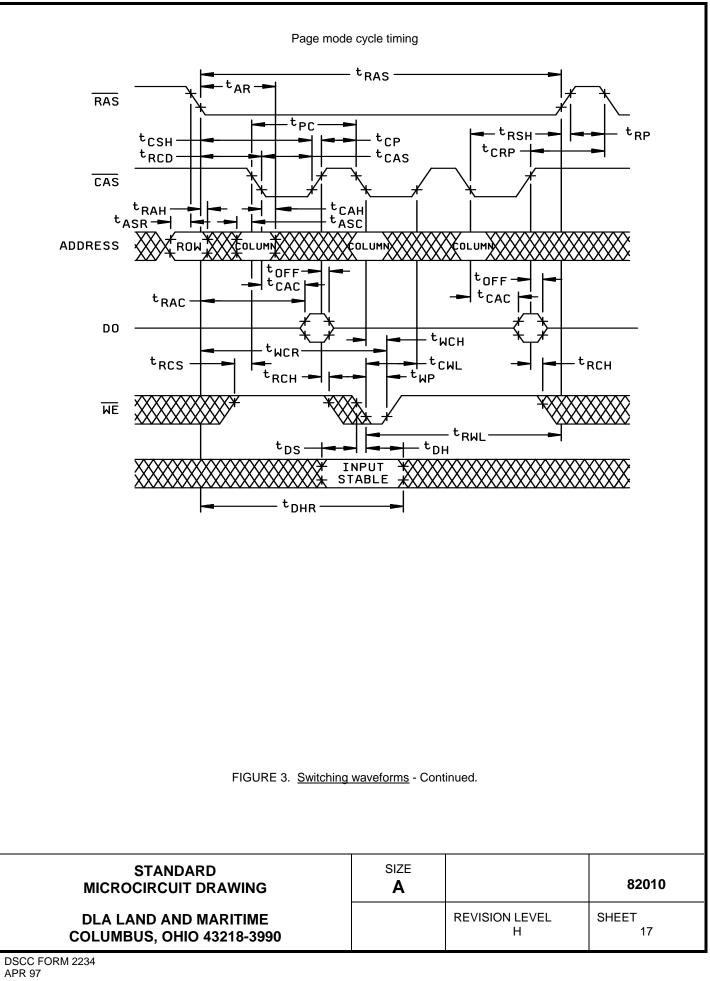


Notes:

- 1. $\overline{CAS} = V_{IH}$; \overline{WRITE} , D_{IN}, A₇ don't care.
- 2. D_{OUT} high impedance.

FIGURE 3. Switching waveforms - Continued.

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4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5, 6, 7, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C₁, C₂ and C_{OUT} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance. Sample size is 5 devices with no failures, and all input and output terminals tested.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition D or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or procuring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractorprepared specification or drawing.

6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.4 <u>Record of users</u>. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime-VA, telephone (614) 692-0544.

6.5 <u>Comments</u>. Comments on this drawing should be directed to DLA Land and Maritime-VA, Columbus, Ohio 43218-3990, or telephone 614-692-0540.

6.6 <u>Approved source of supply</u>. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to DLA Land and Maritime-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 10-11-17

Approved sources of supply for SMD 82010 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime-VA. This information bulletin is superseded by the next dated revisions of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Microcircuit	Vendor	Vendor
drawing part	CAGE	similar part
number <u>1</u> /	number	number 2/
	<u>3</u> /	AM9064-15L/BEA
8201001EA	3/	MKB4564P-82
8201001ZA	3/	MKB4564E-82
	<u> </u>	AM9064-15L/BEA
8201002EA	3/	MKB4564P-82
8201002ZA	3/	MKB4564E-82
	<u>3</u> /	AM9064-20L/BEA
8201003EA	3/	MKB4564P-83
8201003ZA	3/	MKB4564E-83
8201004EA	3/	MT4264C-15
8201004ZA	3/	MT4264EC-15
8201005EA	3/	MT4264C-20
8201005ZA	3/	MT4264EC-20
8201006EA	3V146	4164-15JDS/BEA
	<u>3</u> /	AM9064-15L/BEA
	3/	SMJ4164-15JDS
8201006ZA	<u>3</u> /	SMJ4164-15FGS
	3V146	4164-15FGS/BZA
İ		
8201007EA	3V146	4164-20JDS/BEA
	<u>3</u> /	AM9064-20L/BEA
	3/	SMJ4164-20JDS
8201007ZA	<u>3</u> /	SMJ4164-20FGS
Ì	3V146	4164-20FGS/BZA
8201008EA	3V146	4164-12JDS/BEA
	3/	SMJ4164-12JDS
8201008ZA	<u> 3</u> /	SMJ4164-12FGS
	3V146	4164-12FGS/BZA
8201009EA	<u> 3</u> /	AM9064-15L/BEA
8201010EA	<u>3</u> /	AM9064-20L/BEA
		1

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the Vendor to determine its availability.
- <u>2</u>/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- $\underline{3}$ / No longer available from an approved source.

Vendor CAGE number Vendor name and address

3V146

Rochester Electronics Inc. 16 Malcolm Hoyt Drive Newburyport, MA 01950

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.